

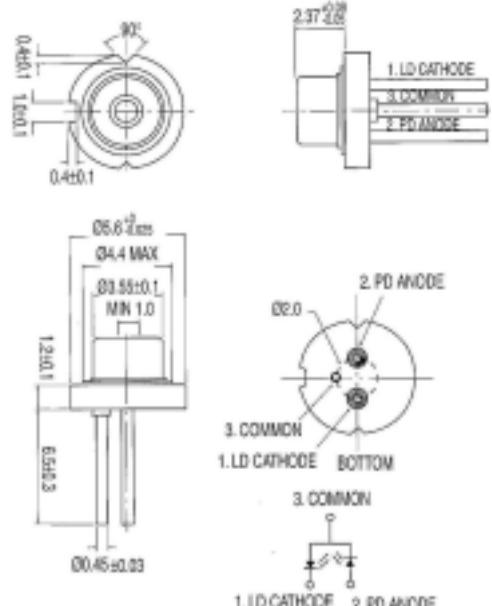


DB LECTRO[®]
COMPOSANTS ÉLECTRONIQUES
ELECTRONIC COMPONENTS

6550-7241-BA 650nm 5 mW Laser Diodes (MANUAL PACKAGE)

Specifications

Device Laser Diode
Package Type TO-18(5.6mm)



Absolute Maximum Ratings(Tc=25 °C)

Characteristics	Symbols	Ratings	Units
Optical Output	Po	7	mW
Reverse Voltage	Laser Vr	2	V
	PIN PD Vr(PIN)	30	V
Operating Temperature	Top	-10 +50	
Operating Temperature(no glass)	Top	0 +40	
Storage Temperature	Tstg	-40 +85	
Storage Temperature(no glass)	Tstg	0 +40	

Electrical and optical Characteristics(Tc=25 °C)

Characteristics	Symbols	Conditions	Min.	Typ.	Max.	Units
Threshold Current	Ith	-	-	20	30	mA
Operating Current	Iop	Po=5mW	-	30	40	mA
Operating Voltage	Vop	Po=5mW	-	2.2	2.6	Volts
Slope Efficiency		2mW	0.3	0.7	1	mW/mA
		I(5mW)-I(3mW)				
Monitor Current	Im	Po=5mW	-	0.2	0.8	mA
Beam Divergence (FWHM)	Parallel	//	Po=5mW	5	8	deg.
	Prependicular		Po=5mW	25	33	deg.
Lasing Wavelength		Po=5mW	645	650	660	nm

Im is sorting by custom's need

// and are defined as the angle within which the intensity is 50% of the peak value.